

# **Maximum Ratings** ( $@T_A = +25^{\circ}C$ , unless otherwise specified.)

Characteristic			Symbol	Value	Unit
Drain-Source Voltage			V <sub>DSS</sub>	20	V
Gate-Source Voltage			V <sub>GSS</sub>	±12	V
Continuous Drain Current (Note 6) V <sub>GS</sub> = 4.5V	Steady State	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	I <sub>D</sub>	14.5 11.5	А
Maximum Continuous Body Diode Forward Current (Note 6)			Is	2.2	Α
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)			I <sub>DM</sub>	75	Α
Avalanche Current (Note 7) L = 0.1mH			I <sub>AS</sub>	10	Α
Avalanche Energy (Note 7) L = 0.1mH			E <sub>AS</sub>	20	mJ

### **Thermal Characteristics**

Characteristic		Symbol	Value	Unit	
Total Power Dissipation (Note 5)	$T_A = +25^{\circ}C$	$P_{D}$	1.0	W	
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	$R_{ heta JA}$	123	°C/W	
Total Power Dissipation (Note 6)	T <sub>A</sub> = +25°C	P <sub>D</sub>	1.7	W	
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	$R_{ heta JA}$	73	°C/W	
Thermal Resistance, Junction to Case	R <sub>θ</sub> JC	12	C/VV		
Operating and Storage Temperature Range		$T_{J_1}T_{STG}$	-55 to +150	°C	

### Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 8)							
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	20	_		V	$V_{GS} = 0V, I_D = 250\mu A$	
Zero Gate Voltage Drain Current T <sub>J</sub> = +25°C	I <sub>DSS</sub>		_	1.0	μA	$V_{DS} = 16V, V_{GS} = 0V$	
Gate-Source Leakage	$I_{GSS}$	-	_	±10	μA	$V_{GS} = \pm 9.6V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 8)							
Gate Threshold Voltage	V <sub>GS(TH)</sub>	0.5	_	1.5	V	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	
		3.5	4.7	5.4		$V_{GS} = 4.5V, I_D = 5.5A$	
		3.6	4.8	6.2		$V_{GS} = 4.0V, I_D = 5.5A$	
Static Drain-Source On-Resistance	R <sub>DS(ON)</sub>	3.7	4.9	6.4	mΩ	$V_{GS} = 3.7V, I_D = 5.5A$	
		3.8	5.1	7.5		$V_{GS} = 3.1V$ , $I_D = 5.5A$	
		3.9	5.7	9.6		$V_{GS} = 2.5V, I_D = 5.5A$	
Diode Forward Voltage	$V_{SD}$		0.7	1.2	V	$V_{GS} = 0V, I_S = 11A$	
DYNAMIC CHARACTERISTICS (Note 9)							
Input Capacitance	C <sub>iss</sub>	I	1,418	l	pF	101/11/	
Output Capacitance	Coss	l	323	1	pF	$V_{DS} = 10V, V_{GS} = 0V,$ f = 1.0MHz	
Reverse Transfer Capacitance	C <sub>rss</sub>	I	106	ı	pF	1 – 1.01011 12	
Gate Resistance	$R_{g}$	I	465	l	Ω	$V_{DS} = 0V$ , $V_{GS} = 0V$ , $f = 1MHz$	
Total Gate Charge (V <sub>GS</sub> = 4.5V)	$Q_g$		18.7	_	nC		
Total Gate Charge (V <sub>GS</sub> = 10V)	$Q_g$	_	42.3	_	nC	\/ 46\/ L 44A	
Gate-Source Charge	Qgs	_	3.2	_	nC	$V_{DS} = 16V, I_{D} = 11A,$	
Gate-Drain Charge	$Q_{gd}$	_	4.4	_	nC	1	
Turn-On Delay Time	t <sub>D(ON)</sub>		277	_	ns		
Turn-On Rise Time	t <sub>R</sub>	_	653	_	ns	$V_{DD} = 16V, I_D = 5.5A,$	
Turn-Off Delay Time	t <sub>D(OFF)</sub>		1,989	_	ns	$V_{GS} = 4.5V, R_g = 6\Omega$	
Turn-Off Fall Time	t <sub>F</sub>		1,208	_	ns	1	
Reverse Recovery Time	t <sub>RR</sub>	_	492	_	ns	1 44 4 41/-14 4004/	
Reverse Recovery Charge	$Q_{RR}$	_	908	_	nC	I <sub>F</sub> =11 A, di/dt = 100A/μs	

Notes: 5. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.

<sup>6.</sup> Device mounted on FR-4 substrate PC board, 2oz copper, with 1-inch square copper plate.

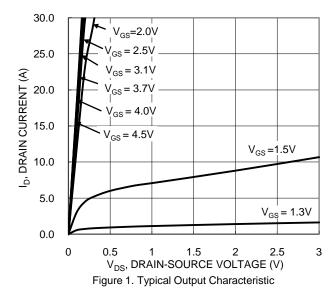
<sup>7.</sup>  $I_{AS}$  and  $E_{AS}$  ratings are based on low frequency and duty cycles to keep  $T_J$  = +25°C.

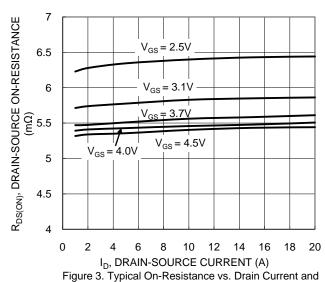
<sup>8.</sup> Short duration pulse test used to minimize self-heating effect.

<sup>9.</sup> Guaranteed by design. Not subject to product testing.

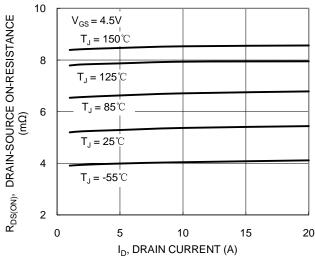


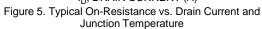






Gate Voltage





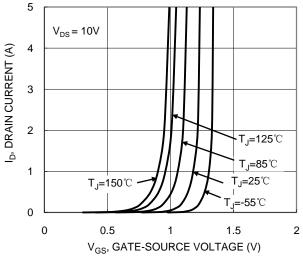


Figure 2. Typical Transfer Characteristic

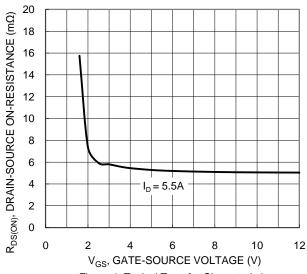
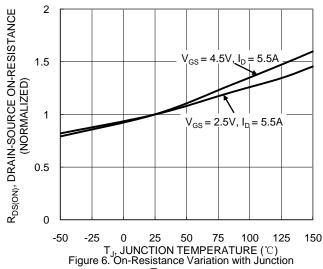


Figure 4. Typical Transfer Characteristic



Temperature



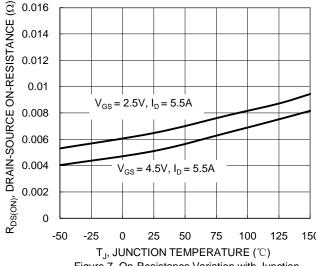
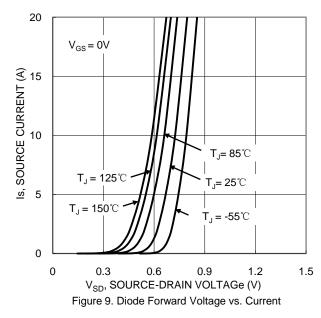


Figure 7. On-Resistance Variation with Junction Temperature



10 9 8 7 6  $V_{GS}(V)$ 5 4 3  $V_{DS} = 16V, I_{D} = 11A$ 2 1 0 0 5 10 20 25 30 35 40 Qg (nC)

Figure 11. Gate Charge

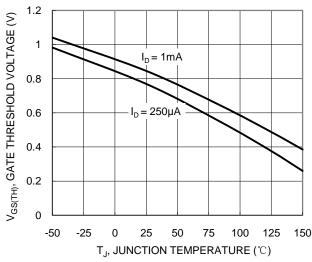
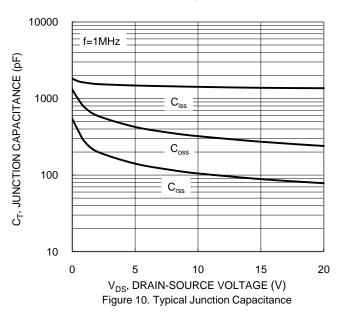
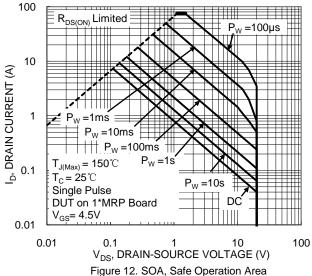
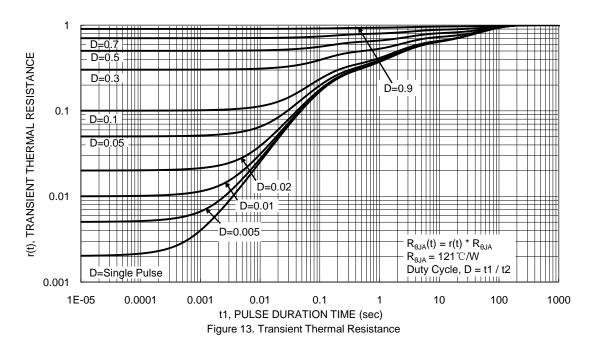


Figure 8. Gate Threshold Variation vs. Junction Temperature







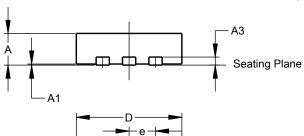


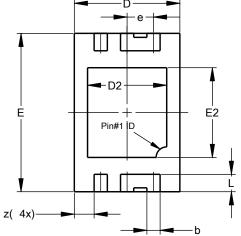


## **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### U-DFN2030-6 (Type B)



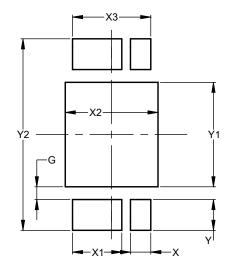


U-DFN2030-6 (Type B)					
Dim	Min	Max	Тур		
Α	0.55	0.65	0.60		
A1	0.00	0.05	0.02		
A3	_	_	0.15		
b	0.20	0.30	0.25		
D	1.95	2.05	2.00		
D2	1.40	1.60	1.50		
Е	2.95	3.05	3.00		
E2	1.65	1.75	1.70		
е	_	_	0.50		
L	0.28	0.38	0.33		
Z	_	_	0.375		
All Dimensions in mm					

## **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### U-DFN2030-6 (Type B)



Dimensions	Value (in mm)			
Dimensions				
G	0.220			
Х	0.350			
X1	0.850			
X2	1.600			
Х3	1.350			
Y	0.530			
Y1	1.800			
Y2	3.300			



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